



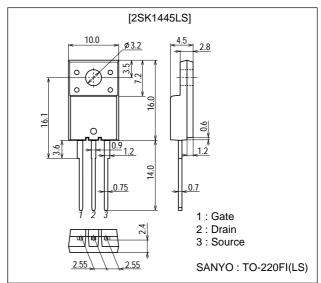
# **Ultrahigh-Speed Switching Applications**

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · Micaless package facilitating mounting.

### **Package Dimensions**

unit : mm 2078C



## **Specifications**

Absolute Maximum Ratings at Ta=25°C

| Parameter                   | Symbol           | Conditions             | Ratings     | Unit |
|-----------------------------|------------------|------------------------|-------------|------|
| Drain-to-Source Voltage     | V <sub>DSS</sub> |                        | 450         | V    |
| Gate-to-Source Voltage      | VGSS             |                        | ±30         | V    |
| Drain Current (DC)          | ID               |                        | 5           | Α    |
| Drain Current (Pulse)       | IDP              | PW≤10μs, duty cycle≤1% | 20          | Α    |
| Allowable Power Dissipation | Do.              |                        | 2.0         | W    |
|                             | PD               | Tc=25°C                | 30          | W    |
| Channel Temperature         | Tch              |                        | 150         | °C   |
| Storage Temperature         | Tstg             |                        | -55 to +150 | °C   |

#### Electrical Characteristics at Ta=25°C

| Parameter                         | Symbol   | Conditions                                | Ratings |     |      | Unit |
|-----------------------------------|----------|---|---------|-----|------|------|
|                                   |          |   | min     | typ | max  | Uill |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I <sub>D</sub> =1mA, V <sub>GS</sub> =0   | 450     |     |      | V    |
| Zero-Gate Voltage Drain Current   | IDSS     | V <sub>DS</sub> =450V, V <sub>GS</sub> =0 |         |     | 1.0  | mA   |
| Gate-to-Source Leakage Current    | IGSS     | V <sub>GS</sub> =±30V, V <sub>DS</sub> =0 |         |     | ±100 | nA   |

 $(Note)\ Be\ careful\ in\ handling\ the\ 2SK1445LS\ because\ it\ has\ no\ protection\ diode\ between\ gate\ and\ source.$ 

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Marking: K1445

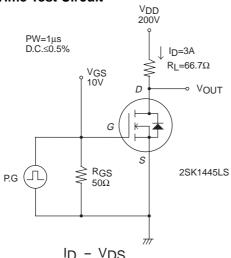
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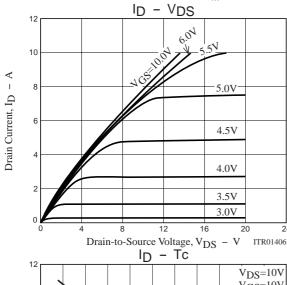
## 2SK1445LS

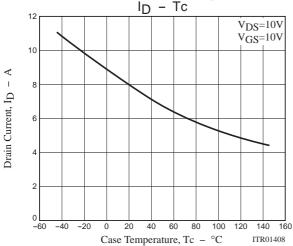
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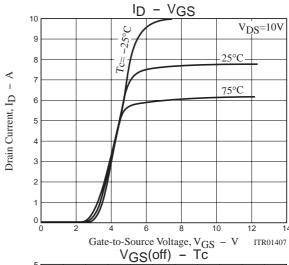
| Parameter                                  | Symbol               | Conditions  | Ratings |     |     | Unit  |
|--|----------------------|---|---------|-----|-----|-------|
|  |                      |   | min     | typ | max | Offic |
| Cutoff Voltage                             | VGS(off)             | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA   | 2.0     |     | 3.0 | V     |
| Forward Transfer Admittance                | yfs                  | V <sub>DS</sub> =10V, I <sub>D</sub> =3A  | 2.0     | 4.0 |     | S     |
| Static Drain-to-Source On-State Resistance | RDS(on)              | ID=3A, VGS=10V  |         | 1.0 | 1.4 | Ω     |
| Input Capacitance                          | Ciss                 | V <sub>DS</sub> =20V, f=1MHz  |         | 700 |     | pF    |
| Output Capacitance                         | Coss                 | V <sub>DS</sub> =20V, f=1MHz  |         | 100 |     | pF    |
| Reverse Transfer Capacitance               | Crss                 | V <sub>DS</sub> =20V, f=1MHz  |         | 40  |     | pF    |
| Turn-ON Delay Time                         | t <sub>d</sub> (on)  | I <sub>D</sub> =3A, V <sub>G</sub> S=10V, V <sub>DD</sub> =200V, R <sub>G</sub> S=50Ω |         | 15  |     | ns    |
| Rise Time                                  | t <sub>r</sub>       | I <sub>D</sub> =3A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 30  |     | ns    |
| Turn-OFF Delay Time                        | t <sub>d</sub> (off) | I <sub>D</sub> =3A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 130 |     | ns    |
| Fall Time                                  | tf                   | I <sub>D</sub> =3A, V <sub>G</sub> S=10V, V <sub>DD</sub> =200V, R <sub>G</sub> S=50Ω |         | 45  |     | ns    |
| Diode Forward Voltage                      | V <sub>SD</sub>      | I <sub>S</sub> =5A, V <sub>G</sub> S=0  |         |     | 1.8 | V     |

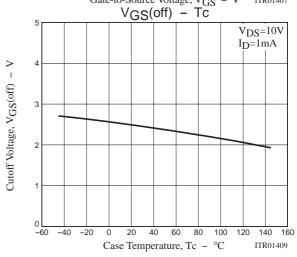
## **Switching Time Test Circuit**

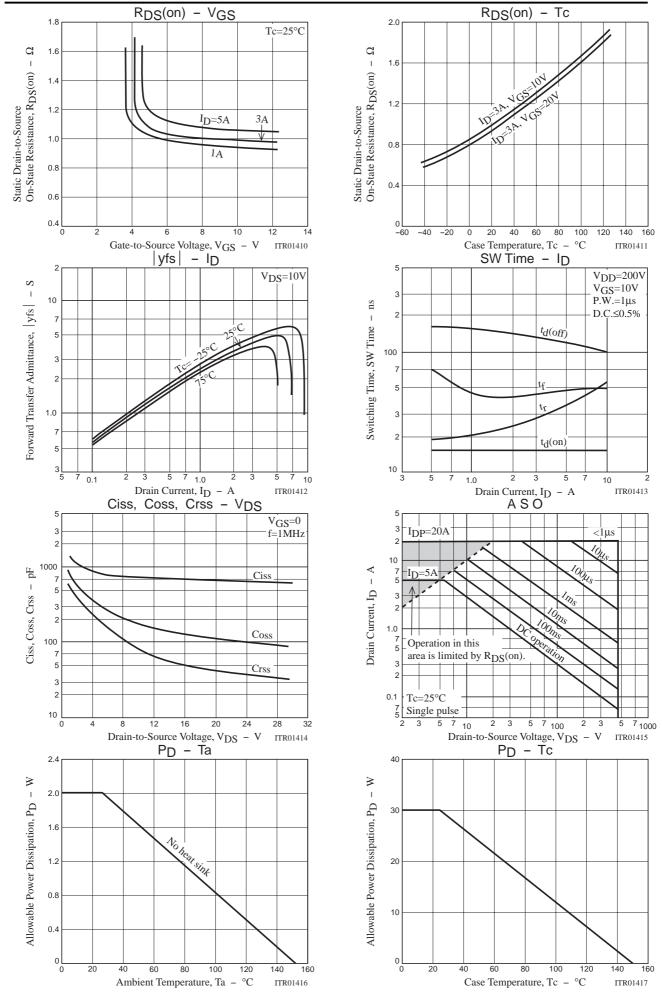












#### 2SK1445LS

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